

Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company





PNP SILICON PLANAR TRANSISTOR



2N995

TO-18 Metal Can Package

ABSOLUTE MAXIMUM RATINGS (T_a =25° C unless specified otherwise)

DESCRIPTION	SYMBOL	2N995	UNITS
Collector Emitter Voltage	V _{CEO}	15	V
Collector Base Voltage	V _{CBO}	20	V
Emitter Base Voltage	V _{EBO}	4	V
Collector Current Continuous	I _C	200	mA
Power Dissipation at T_{a} = 25° C	D D	0.36	W
at T _C = 25° C	P _D	1.2	W
Operating And Storage Junction Temperature Range		-65 to +200	° C

ELECTRICAL CHARACTERISTICS (T_a =25° C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Collector Emitter Voltage	V_{CEO}	I _C = 1mA, I _B = 0	15			V
Collector Base Voltage V _{CBO}		I _C = 10μΑ, I _E = 0	20			V
Emitter Base Voltage	V _{EBO}	I _C = 10μA, I _B = 0	4			V
Collector Cut Off Current	I _{CBO}	V _{CB} = 15V, I _E = 0			5	nA
Collector Cut Off Current		V _{CB} = 15V,T _a = 150° C			25	μΑ
Emitter leakage current I _{EBO}		$V_{EB} = 4V$, $I_{B} = 0$			10	μΑ
Collector Emitter Saturation Voltage	V _{CE(Sat)}	I _C = 10mA, I _B = 1mA			0.2	V
Base Emitter Saturation Voltage V _{BE(Sat)}		I _C = 10mA, I _B = 1mA			0.95	V
DC Current Gain	*hFE	I _C = 1mA, V _{CE} = 1V	25			
		I _C = 20mA, V _{CE} = 1V	35		140	
		I _C = 50mA, V _{CE} = 1V	25			

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DYNAMIC CHARACTERISTICS

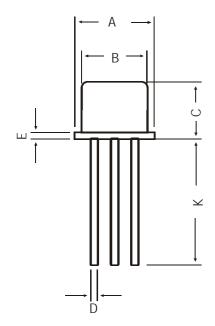
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Transistor Frequency	f _T	$I_{C} = 10 \text{mA}, V_{CE} = 15 \text{ V},$ f = 100 MHz	100			MHz
Input Capacitance	C _{ib}	V _{BE} =0.5V, I _C =0			11	pF
Output Capacitance	C _{ob}	V _{CB} =10V, I _E =0			10	pF

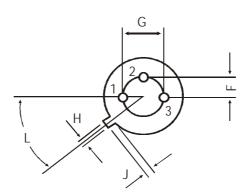
^{*} Pulse Condition : Length≤ 300μS, Duty Cycle ≤ 1%

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	DIM	MIN	MAX		
	Α	5.24	5.84		
	В	4.52	4.97		
	С	4.31	5.33		
	D	0.40	0.53		
	E	ı	0.76		
Ϊ.	F	ı	1.27		
=	G	ı	2.97		
SIIS	Н	0.91	1.17		
1121	J	0.71	1.21		
All dillilisiolis III IIIII	K	12.70			
H	L	45 E	DEG		



PIN CONFIGURATION

- 1. EMITTER
- 2. BASE3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTO	N BOX	OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-18	1K/polybag	350 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	34 kgs

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Notes 2N995

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Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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